



## TO-220 Plastic-Encapsulated Transistors

### TIP31/31A/31B/31C TRANSISTOR (NPN)

#### FEATURES

Power dissipation

$$P_{CM}: 2 \text{ W (Tamb=25}^\circ\text{C)}$$

Collector current

$$I_{CM}: 3 \text{ A}$$

Collector-base voltage

$$V_{(BR)CBO}: \begin{array}{ll} \text{TIP31:} & 40 \text{ V} \\ \text{TIP31A:} & 60 \text{ V} \\ \text{TIP31B:} & 80 \text{ V} \\ \text{TIP31C:} & 100 \text{ V} \end{array}$$

Operating and storage junction temperature range

$$T_J, T_{stg}: -55^\circ\text{C to } +150^\circ\text{C}$$

#### ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

| Parameter  | Symbol        | Test conditions   | MIN                   | MAX        | UNIT |
|--|---------------|---|-----------------------|------------|------|
| Collector-base breakdown voltage<br>31<br>31A<br>31B<br>31C    | $V_{(BR)CBO}$ | $I_C = 100 \mu\text{A}, I_E = 0$  | 40<br>60<br>80<br>100 |            | V    |
| Collector-emitter breakdown voltage<br>31<br>31A<br>31B<br>31C | $V_{(BR)CEO}$ | $I_C = 30 \text{ mA}, I_B = 0$  | 40<br>60<br>80<br>100 |            | V    |
| Emitter-base breakdown voltage                                 | $V_{(BR)EBO}$ | $I_E = 100 \mu\text{A}, I_C = 0$  | 5                     |            | V    |
| Collector cut-off current<br>31<br>31A<br>31B<br>31C           | $I_{CBO}$     | $V_{CB} = 40\text{V}, I_E = 0$<br>$V_{CB} = 60\text{V}, I_E = 0$<br>$V_{CB} = 80\text{V}, I_E = 0$<br>$V_{CB} = 100\text{V}, I_E = 0$ |                       | 0.2        | mA   |
| Collector cut-off current<br>31/31A<br>31B/31C                 | $I_{CEO}$     | $V_{CE} = 30\text{V}, I_B = 0$<br>$V_{CE} = 60\text{V}, I_B = 0$  |                       | 0.3<br>0.3 | mA   |
| Emitter cut-off current  | $I_{EBO}$     | $V_{EB} = 5\text{V}, I_C = 0$   |                       | 1          | mA   |
| DC current gain  | $h_{FE(1)}$   | $V_{CE} = 4\text{V}, I_C = 3\text{A}$   | 10                    | 50         |      |
|  | $h_{FE(2)}$   | $V_{CE} = 4\text{V}, I_C = 1\text{A}$   | 25                    |            |      |
| Collector-emitter saturation voltage                           | $V_{CE(sat)}$ | $I_C = 3\text{A}, I_B = 375\text{mA}$   |                       | 1.2        | V    |
| Base-emitter voltage   | $V_{BE(on)}$  | $V_{CE} = 4\text{V}, I_C = 3\text{A}$   |                       | 1.8        | V    |
| Transition frequency   | $f_T$         | $V_{CE} = 10\text{V}, I_C = 500\text{mA}$   | 3                     |            | MHz  |

